1 GHz, 23 dB gain GaAs push-pull amplifier Rev. 1 — 10 February 2011

Product data sheet

#### **Product profile** 1.

## **1.1 General description**

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V Direct Current (DC), employing Heterojunction Field Effect Transistor (HFET) GaAs dies.

## 1.2 Features and benefits

- Excellent linearity, stability and reliability
- Extremely low noise
- Excellent return loss properties
- Rugged construction
- Unconditionally stable
- Thermally optimized design
- Superior levels of ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)
- Integrated ring wave surge protection
- Power gain is specified for both 870 MHz and 1003 MHz bandwidth

## 1.3 Applications

CATV systems operating in the 40 MHz to 1003 MHz frequency range

## 1.4 Quick reference data

#### **Quick reference data** Table 1.

Bandwidth 40 MHz to 1003 MHz;  $V_B = 24 V (DC)$ ;  $Z_S = Z_L = 75 \Omega$ ;  $T_{mb} = 35$ °C; unless otherwise specified.

| Symbol           | Parameter                  | Conditions              | Min          | Тур   | Мах  | Unit |
|------------------|----------------------------|-------------------------|--------------|-------|------|------|
| Gp               | power gain                 | f = 45 MHz              | 21.0         | 22.0  | 23.0 | dB   |
|                  |                            | f = 870 MHz             | 22.3         | 23.3  | 24.3 | dB   |
|                  |                            | f = 1003 MHz            | 23.0         | 23.75 | 24.5 | dB   |
| СТВ              | composite triple beat      | $V_o = 44 \text{ dBmV}$ | <u>[1]</u> - | -62   | -    | dBc  |
| CCN              | carrier-to-composite noise | $V_o = 44 \text{ dBmV}$ | <u>[1]</u> _ | 63    | -    | dBc  |
| I <sub>tot</sub> | total current              |                         | [2] _        | 265   | 280  | mA   |

[1] 79 NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat output level.

[2] Direct Current (DC).



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## 2. Pinning information

| Table 2. | Pinning         |                                   |
|----------|-----------------|-----------------------------------|
| Pin      | Description     | Simplified outline Graphic symbol |
| 1        | input           |                                   |
| 2, 3     | common          |                                   |
| 5        | +V <sub>B</sub> |                                   |
| 7, 8     | common          |                                   |
| 9        | output          | sym095                            |

## 3. Ordering information

| Table 3. Orde | ering inform | ation   |         |
|---------------|--------------|---|---------|
| Type number   | Package      |   |         |
|               | Name         | Description   | Version |
| CGY1043       | -            | rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads | SOT115J |

## 4. Limiting values

#### Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol             | Parameter                       | Conditions  |            | Min | Max  | Unit |
|--------------------|---------------------------------|---|------------|-----|------|------|
| VB                 | supply voltage                  |   |            | -   | 30   | V    |
| V <sub>i(RF)</sub> | RF input voltage                | single tone   |            | -   | 75   | dBmV |
| V <sub>ESD</sub>   | electrostatic discharge voltage | Human Body Model (HBM);<br>According JEDEC standard<br>22-A114E | <u>[1]</u> | -   | 2000 | V    |
|                    |                                 | Biased; According<br>IEC61000-4-2                               |            | -   | 2000 | V    |
| T <sub>stg</sub>   | storage temperature             |   |            | -40 | +100 | °C   |
| T <sub>mb</sub>    | mounting base temperature       |   |            | -20 | +100 | °C   |

[1] The value of 2000 V corresponds to a class 2 classification.

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## 5. Characteristics

#### Table 5. Characteristics

Bandwidth 40 MHz to 1003 MHz;  $V_B = 24 V (DC)$ ;  $Z_S = Z_L = 75 \Omega$ ;  $T_{mb} = 35 °C$ ; unless otherwise specified.

| Symbol            | Parameter                         | Conditions               | Min                  | Тур   | Max  | Unit |
|-------------------|-----------------------------------|--------------------------|----------------------|-------|------|------|
| G <sub>p</sub>    | power gain                        | f = 45 MHz               | 21.0                 | 22.0  | 23.0 | dB   |
|                   |                                   | f = 870 MHz              | 22.3                 | 23.3  | 24.3 | dB   |
|                   |                                   | f = 1003 MHz             | 23.0                 | 23.75 | 24.5 | dB   |
| SL <sub>sl</sub>  | slope straight line               | f = 45 MHz to 1003 MHz   | <mark>[1]</mark> 1.2 | 1.95  | 2.7  | dB   |
| FL                | flatness of frequency response    | f = 45 MHz to 1003 MHz   | [2] _                | -     | 0.9  | dB   |
| RL <sub>in</sub>  | input return loss                 | f = 45 MHz to 200 MHz    | 20                   | -     | -    | dB   |
|                   |                                   | f = 200 MHz to 550 MHz   | 19                   | -     | -    | dB   |
|                   |                                   | f = 550 MHz to 870 MHz   | 19                   | -     | -    | dB   |
|                   |                                   | f = 870 MHz to 914 MHz   | 19                   | -     | -    | dB   |
|                   |                                   | f = 914 MHz to 1003 MHz  | 16                   | -     | -    | dB   |
| RL <sub>out</sub> | output return loss                | f = 45 MHz to 200 MHz    | 18                   | -     | -    | dB   |
|                   |                                   | f = 200 MHz to 550 MHz   | 18                   | -     | -    | dB   |
|                   |                                   | f = 550 MHz to 870 MHz   | 18                   | -     | -    | dB   |
|                   |                                   | f = 870 MHz to 914 MHz   | 18                   | -     | -    | dB   |
|                   |                                   | f = 914 MHz to 1003 MHz  | 16                   | -     | -    | dB   |
| NF                | noise figure                      | f = 50 MHz               | -                    | 3.5   | 4.0  | dB   |
|                   |                                   | f = 1003 MHz             | -                    | 4.2   | 4.9  | dB   |
| I <sub>tot</sub>  | total current                     |                          | <u>[3]</u> _         | 265   | 280  | mA   |
| <b>79 NTSC</b>    | channels + 75 digital channels    |                          |                      |       |      |      |
| СТВ               | composite triple beat             | V <sub>o</sub> = 44 dBmV | [4] _                | -62   | -    | dBc  |
| CSO               | composite second-order distortion | V <sub>o</sub> = 44 dBmV | [4] _                | -64   | -    | dBc  |
| Xmod              | cross modulation                  | V <sub>o</sub> = 44 dBmV | [4] _                | -58   | -    | dB   |
| CCN               | carrier-to-composite noise        | $V_o = 44 \text{ dBmV}$  | [4] _                | 63    | -    | dBc  |
| <b>79 NTSC</b>    | channels                          |                          |                      |       |      |      |
| СТВ               | composite triple beat             | $V_o = 44 \text{ dBmV}$  | <u>[5]</u>           | -     | -62  | dBc  |
| CSO               | composite second-order distortion | V <sub>o</sub> = 44 dBmV | [5] _                | -     | -62  | dBc  |
| Xmod              | cross modulation                  | $V_o = 44 \text{ dBmV}$  | <u>[5]</u> _         | -58   | -    | dB   |
| 98 PAL o          | channels                          |                          |                      |       |      |      |
| СТВ               | composite triple beat             | V <sub>o</sub> = 44 dBmV | [6] _                | -68   | -    | dBc  |
| CSO               | composite second-order distortion | V <sub>o</sub> = 44 dBmV | [6] _                | -66   | -    | dBc  |
| Xmod              | cross modulation                  | V <sub>o</sub> = 44 dBmV | [6] _                | -58   | -    | dB   |

[1]  $G_p$  at 1003 MHz minus  $G_p$  at 45 MHz.

[2] Flatness is defined as maximum deviation to straight line.

www[3] Direct Current (DC).

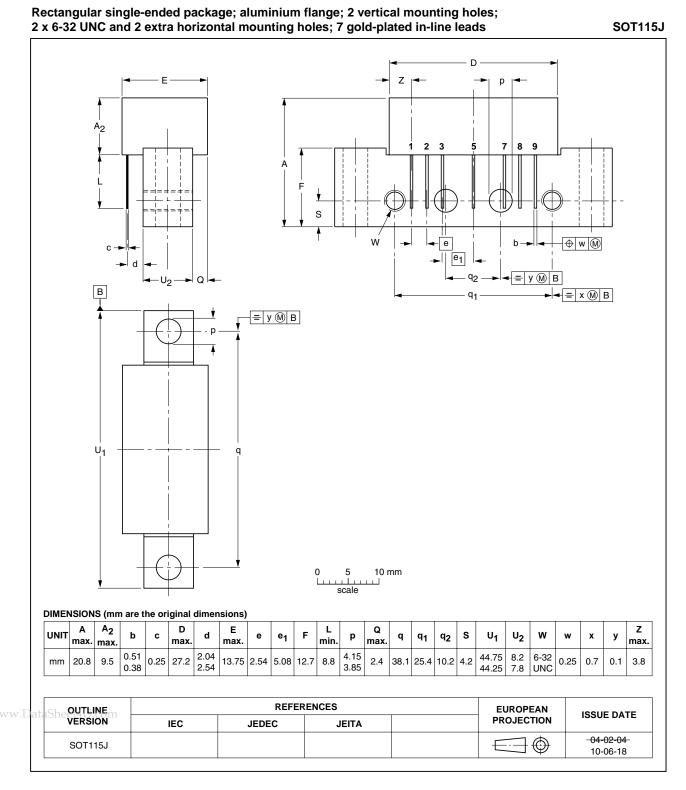
[4] 79 NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat output level.

[5] 79 NTSC channels [f = 55.25 MHz to 550 MHz]; flat output level.

 $[6] \quad 98 \ \text{PAL channels} \ [f = 49.75 \ \text{MHz} \ \text{to} \ 847.25 \ \text{MHz}]; \ \text{flat output level}.$ 

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## 6. Package outline



#### Fig 1. Package outline SOT115J

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CGY1043

1 GHz, 23 dB gain GaAs push-pull amplifier

## 7. Abbreviations

| Table 6. | Abbreviations                          |
|----------|--|
| Acronym  | Description                            |
| CATV     | Community Antenna TeleVision           |
| ESD      | ElectroStatic Discharge                |
| GaAs     | Gallium Arsenide                       |
| NTSC     | National Television Standard Committee |
| PAL      | Phase Alternating Line                 |
| RF       | Radio Frequency                        |
| UNC      | UNified Coarse                         |
|          |  |

## 8. Revision history

| Table 7. Revision history |              |                    |               |            |
|---------------------------|--------------|--------------------|---------------|------------|
| Document ID               | Release date | Data sheet status  | Change notice | Supersedes |
| CGY1043 v.1               | 20110210     | Product data sheet | -             | -          |

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## 9. Legal information

## 9.1 Data sheet status

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet   | Development                   | This document contains data from the objective specification for product development. |
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| Product [short] data sheet     | Production                    | This document contains the product specification.                                     |

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